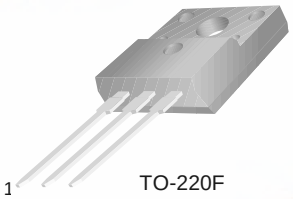
FAIRCHILD SEMICONDUCTOR TM

KSC5039F

High Voltage Power Switch Switching Application



TO-220F

1.Base 2.Collector 3.Emitter

NPN Planar Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	800	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	5	A
I_{CP}	Collector Current (Pulse)	10	A
I_B	Base Current	3	A
P_C	Collector Dissipation (T_C=25°C)	30	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 1mA, I_E = 0	800			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 5mA, I_B = 0	400			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_C = 1mA, I_C = 0	7			
I_{CBO}	Collector Cut-off Current	V_{CB} = 500V, I_E = 0			10	μA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 7V, I_C = 0			10	μA
h_{FE}	*DC Current Gain	V_{CE} = 5V, I_C = 0.3A	10			
V_{CE}(sat)	*Collector-Emitter Saturation Voltage	I_C = 2.5A, I_B = 0.5A			1.5	V
V_{BE}(sat)	*Base-Emitter Saturation Voltage	I_C = 2.5A, I_B = 0.5A			2.0	V
f_T	Current Gain Bandwidth Product	V_{CE} = 5V, I_C = 0.1A		10		MHz
C_{ob}	Output Capacitance	V_{CB} = 10V , f = 1MHz		40		pF
t_{ON}	Turn ON Time	V_{CC}=150V , I_C = 2.5A, I_{B1} = -I_{B2} = 0.5A R_L = 60Ω			1	μs
t_{STG}	Storage Time				3	μs
t_F	Fall Time				0.8	μs

* Plus test: PW=300μs, Duty Cycle=2% Pulsed

Typical Characteristics

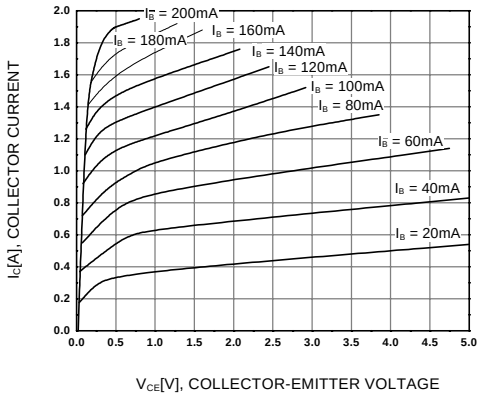


Figure 1. Static Characteristic

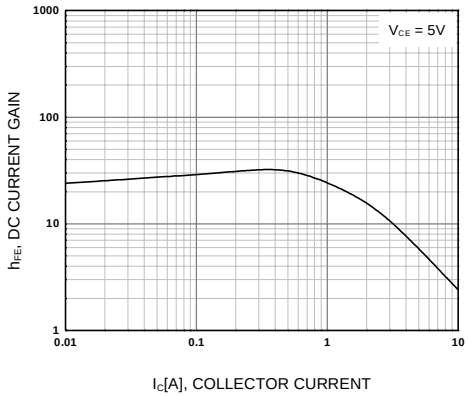


Figure 2. DC current Gain

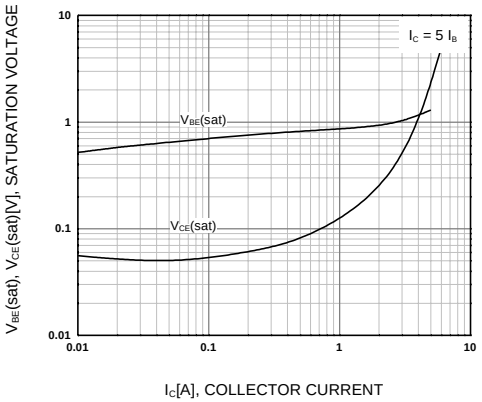


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

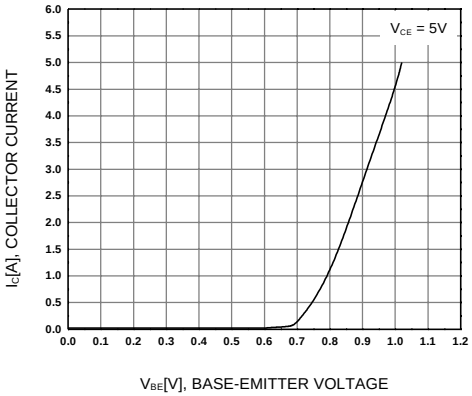


Figure 4. Base-Emitte On Voltage

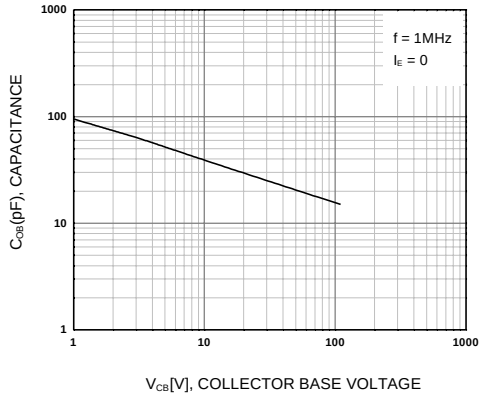


Figure 5. Collector Output Capacitance

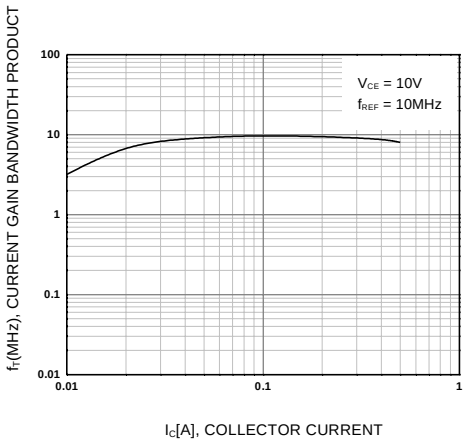


Figure 6. Current Gain Bandwidth Product

Typical Characteristics (Continued)

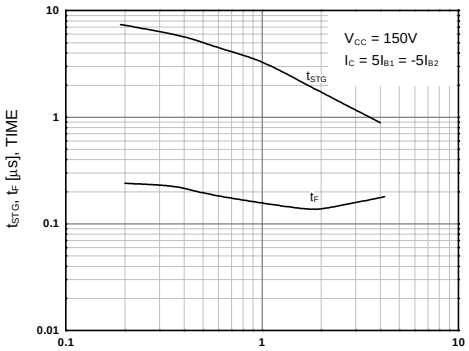


Figure 7. Switching Time

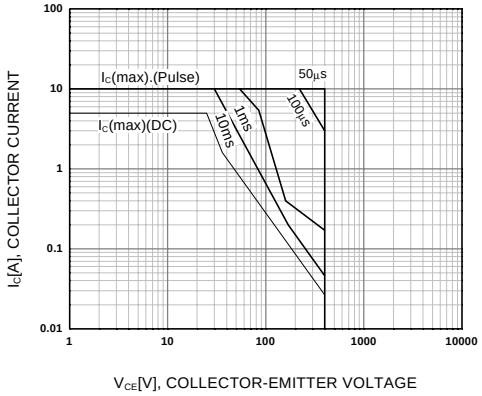


Figure 8. Safe Operating Area

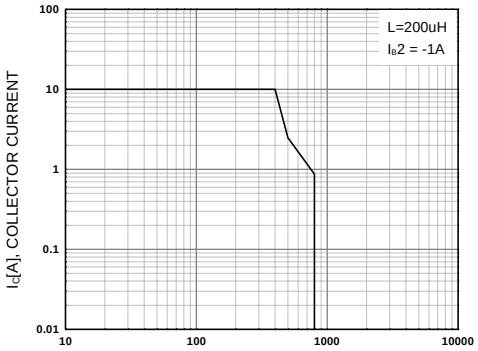


Figure 9. Reverse Bias Safe Operaing Area

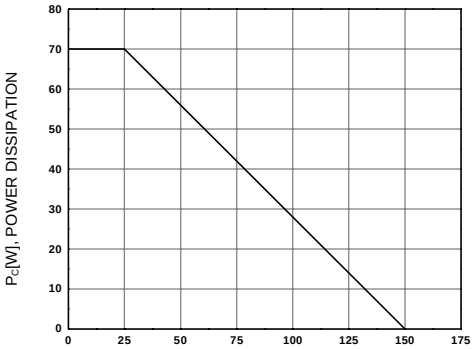
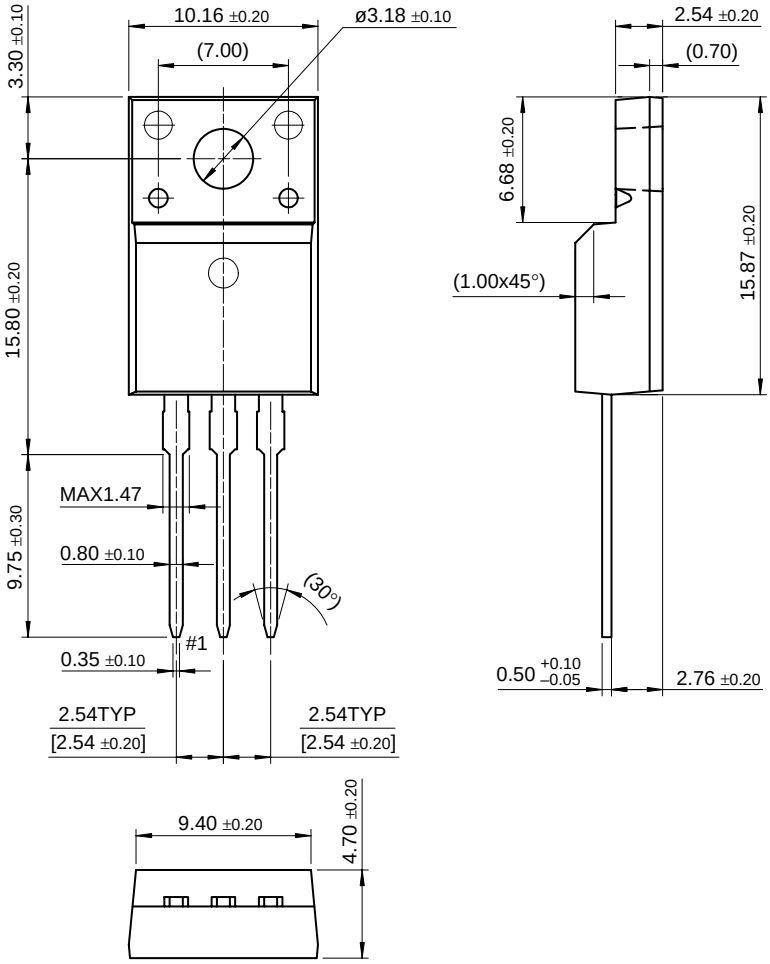


Figure 10. Power Derating

Package Demensions

TO-220F



Dimensions in Millimeters

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